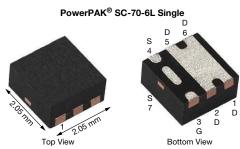


# P-Channel 20 V (D-S) MOSFET



Marking code: BK

PRODUCT SUMMARY	
V <sub>DS</sub> (V)	-20
$R_{DS(on)}$ max. ( $\Omega$ ) at $V_{GS} = -4.5 \text{ V}$	0.025
$R_{DS(on)}$ max. ( $\Omega$ ) at $V_{GS} = -2.5 \text{ V}$	0.031
$R_{DS(on)}$ max. ( $\Omega$ ) at $V_{GS} = -1.8 \text{ V}$	0.041
$R_{DS(on)}$ max. ( $\Omega$ ) at $V_{GS} = -1.5 \text{ V}$	0.070
Q <sub>g</sub> typ. (nC)	24
I <sub>D</sub> (A) <sup>a</sup>	-12
Configuration	Single

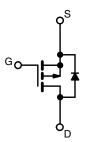
#### **FEATURES**

- TrenchFET® power MOSFET
- New thermally enhanced PowerPAK® SC-70 package
  - Small footprint area
  - Low on-resistance
- 100 % R<sub>q</sub> tested
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



### **APPLICATIONS**

· Load switch, PA switch and battery switch for portable devices



P-Channel MOSFET

ORDERING INFORMATION							
Package	PowerPAK SC-70						
Load (Dh) froe and helegan free	SiA431DJ-T1-GE3						
Lead (Pb)-free and halogen-free	SiA431DJ-T4-GE3						

<b>ABSOLUTE MAXIMUM RATINGS</b>	(T <sub>A</sub> = 25 °C, unless	s otherwise noted	d)			
PARAMETER		SYMBOL	LIMIT	UNIT		
Drain-source voltage		V <sub>DS</sub>	-20	V		
Gate-source voltage		$V_{GS}$	± 8	v		
	T <sub>C</sub> = 25 °C		-12 <sup>a</sup>			
O a 11' a a a a 1 a 1' a a a a 1 a 1' a 1 a 1	T <sub>C</sub> = 70 °C		-12 <sup>a</sup>			
Continuous drain current (T <sub>J</sub> = 150 °C)	T <sub>A</sub> = 25 °C	l <sub>D</sub>	-9.6 <sup>b, c</sup>			
	T <sub>A</sub> = 70 °C		-7.7 <sup>b, c</sup>	A		
Pulsed drain current		I <sub>DM</sub>	-30			
Continuous autorio dia da autorio	T <sub>C</sub> = 25 °C		-12 <sup>a</sup>			
Continuous source-drain diode current	T <sub>A</sub> = 25 °C	l <sub>s</sub>	-2.9 <sup>b, c</sup>			
	T <sub>C</sub> = 25 °C		19	w		
Maximum navver dissination	T <sub>C</sub> = 70 °C		12			
Maximum power dissipation	T <sub>A</sub> = 25 °C	P <sub>D</sub>	3.5 b, c			
	T <sub>A</sub> = 70 °C		2.2 b, c			
Operating junction and storage temperature ra	nge	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	00		
Soldering recommendations (peak temperature	e) <sup>d, e</sup>		260	°C		

THERMAL RESISTANCE RATINGS									
PARAMETER	SYMBOL	TYPICAL	MAXIMUM	UNIT					
Maximum junction-to-ambient b, f	t ≤ 5 s	R <sub>thJA</sub>	28	36	°C/W				
Maximum junction-to-case (drain)	Steady state	$R_{thJC}$	5.3	6.5	C/VV				

#### **Notes**

- a. Package limited
- b. Surface mounted on 1" x 1" FR4 board
- c. t = 5 s
- 6. 1–33
  6. See solder profile (<a href="www.vishay.com/doc?73257">www.vishay.com/doc?73257</a>). The PowerPAK SC-70 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components
- f. Maximum under steady state conditions is 80 °C/W

# Vishay Siliconix

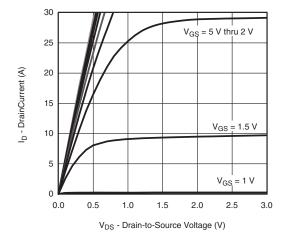
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static					L	l	
Drain-source breakdown voltage	$V_{DS}$	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	-20	-	-	V	
V <sub>DS</sub> temperature coefficient	$\Delta V_{DS}/T_{J}$		-	-14.5	-		
V <sub>GS(th)</sub> temperature coefficient	$\Delta V_{GS(th)}/T_J$	I <sub>D</sub> = -250 μA	-	2.7	-	mV/°C	
Gate-source threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	-0.4	-	-0.85	V	
Gate-source leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$	-	-	± 100	nA	
		$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	-1		
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = -20 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 55 °C	-	-	-10	μA	
On-state drain current a	I <sub>D(on)</sub>	$V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	-20	-	-	Α	
	= (0.1)	$V_{GS} = -4.5 \text{ V}, I_D = -6.5 \text{ A}$	-	0.020	0.025	<del></del>	
	_	V <sub>GS</sub> = -2.5 V, I <sub>D</sub> = -5.8 A	-	0.025	0.031	_	
Drain-source on-state resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> = -1.8 V, I <sub>D</sub> = -2.5 A	-	0.034	0.041	Ω	
		V <sub>GS</sub> = -1.5 V, I <sub>D</sub> = -1.5 A	-	0.045	0.070		
Forward transconductance a	9 <sub>fs</sub>	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -6.5 A	-	31	-	S	
Dynamic <sup>b</sup>	, one			l	l.	l	
Input capacitance	C <sub>iss</sub>		-	1700	-	pF	
Output capacitance	Coss	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	-	230	-		
Reverse transfer capacitance	C <sub>rss</sub>	, 45	-	205	-		
<u> </u>		V <sub>DS</sub> = -10 V, V <sub>GS</sub> = -8 V, I <sub>D</sub> = -9.6 A	-	40	60	1	
Total gate charge	$Q_g$ $Q_{gs}$ $Q_{ad}$		-	24	36	nC	
Gate-source charge		$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -9.6 \text{ A}$	-	2.4	-		
Gate-drain charge		30 . 00	-	6.5	-		
Gate resistance	Ra	f = 1 MHz	1.3	6.3	13	Ω	
Turn-on delay time	t <sub>d(on)</sub>		-	22	35		
Rise time	t <sub>r</sub>	$V_{DD} = -10 \text{ V}, R_L = 1.3 \Omega,$	-	25	40		
Turn-off delay time	t <sub>d(off)</sub>	$I_D \cong -7.7 \text{ A}, V_{GEN} = -4.5 \text{ V}, R_g = 1 \Omega$	-	65	100		
Fall time	t <sub>f</sub>		-	25	40		
Turn-on delay time	t <sub>d(on)</sub>		-	10	15		
Rise time	$t_r$ $V_{DD} = -10 \text{ V}, R_L = 1.3 \Omega,$		-	10	15		
Turn-off delay time	t <sub>d(off)</sub>	$I_D \cong -7.7 \text{ A, } V_{GEN} = -8 \text{ V, } R_g = 1 \Omega$	-	65	100		
Fall time	t <sub>f</sub>		-	20	30		
Drain-Source Body Diode Characterist	ics			l	l.		
Continuous source-drain diode current	Is	T <sub>C</sub> = 25 °C	-	-	-12	_	
Pulse diode forward current	I <sub>SM</sub>	-	-	-	-30	A	
Body diode voltage	V <sub>SD</sub>	I <sub>S</sub> = -7.7 A, V <sub>GS</sub> = 0 V	-	-0.8	-1.2	V	
Body diode reverse recovery time			-	35	60	ns	
Body diode reverse recovery charge	Q <sub>rr</sub>	I <sub>F</sub> = -7.7 A, di/dt = 100 A/μs,	-	21	35	nC	
Reverse recovery fall time	ta	$T_{\rm J} = 25  ^{\circ}{\rm C}$	-	20	-	1	
· · · · · · · · · · · · · · · · · · ·	a			1	1	ns	

#### Notes

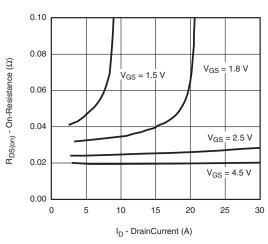
- a. Pulse test; pulse width  $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

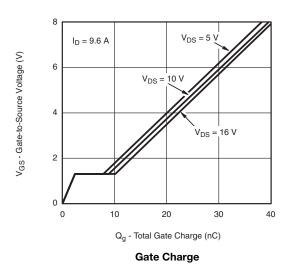


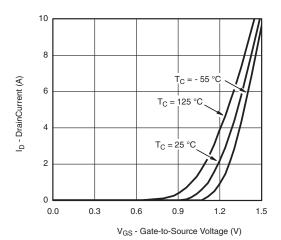


#### **Output Characteristics**

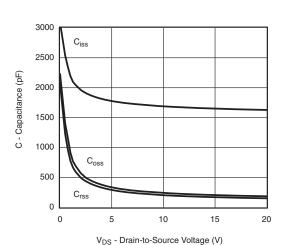


### On-Resistance vs. Drain Current and Gate Voltage

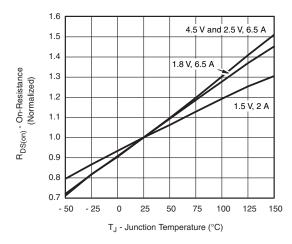




#### **Transfer Characteristics**

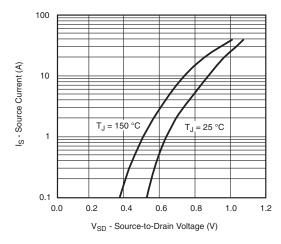


Capacitance

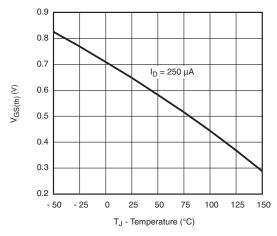


On-Resistance vs. Junction Temperature

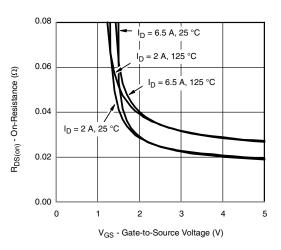




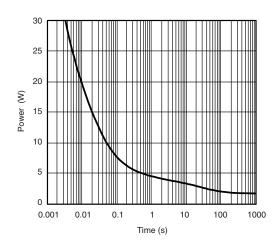
#### Source-Drain Diode Forward Voltage



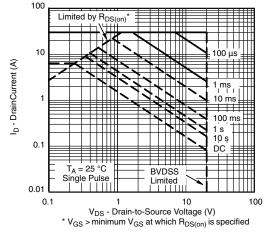
**Threshold Voltage** 



On-Resistance vs. Gate-to-Source Voltage

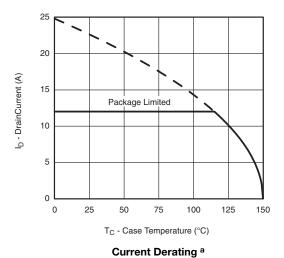


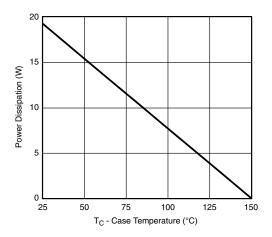
Single Pulse Power, Junction-to-Ambient



Safe Operating Area, Junction-to-Ambient





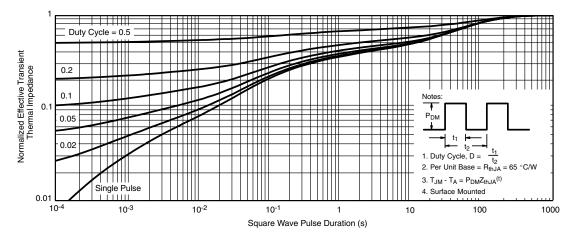


**Power Derating** 

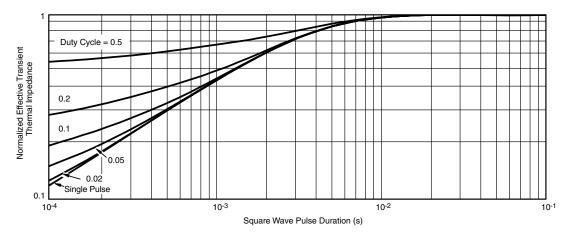
#### Note

a. The power dissipation  $P_D$  is based on  $T_J$  max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit





Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

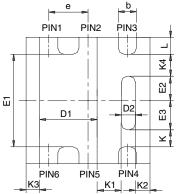
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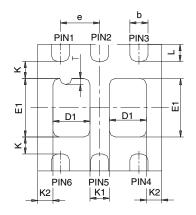




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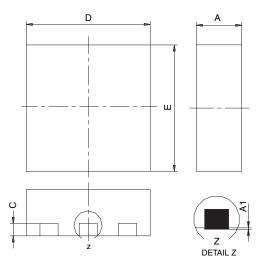
# PowerPAK® SC70-6L





BACKSIDE VIEW OF SINGLE

BACKSIDE VIEW OF DUAL



- All dimensions are in millimeters
   Package outline exclusive of mold flash and metal burr
   Package outline inclusive of plating

	SINGLE PAD						DUAL PAD					
DIM	M	ILLIMETER	RS		INCHES		М	ILLIMETER	RS		INCHES	
	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max
Α	0.675	0.75	0.80	0.027	0.030	0.032	0.675	0.75	0.80	0.027	0.030	0.032
<b>A</b> 1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
b	0.23	0.30	0.38	0.009	0.012	0.015	0.23	0.30	0.38	0.009	0.012	0.015
С	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010
D	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
D1	0.85	0.95	1.05	0.033	0.037	0.041	0.513	0.613	0.713	0.020	0.024	0.028
D2	0.135	0.235	0.335	0.005	0.009	0.013						
E	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
E1	1.40	1.50	1.60	0.055	0.059	0.063	0.85	0.95	1.05	0.033	0.037	0.041
E2	0.345	0.395	0.445	0.014	0.016	0.018						
E3	0.425	0.475	0.525	0.017	0.019	0.021						
е		0.65 BSC			0.026 BSC	;		0.65 BSC			0.026 BSC	
K		0.275 TYP			0.011 TYP	1	0.275 TYP			0.011 TYP		
K1		0.400 TYP			0.016 TYP		0.320 TYP			0.013 TYP		
K2		0.240 TYP		0.009 TYP		0.252 TYP			0.010 TYP			
К3		0.225 TYP		0.009 TYP								
K4		0.355 TYP			0.014 TYP							
L	0.175	0.275	0.375	0.007	0.011	0.015	0.175	0.275	0.375	0.007	0.011	0.015
Т							0.05	0.10	0.15	0.002	0.004	0.006
ECN: C O	2.07421 Pay C 06 Aug 07											

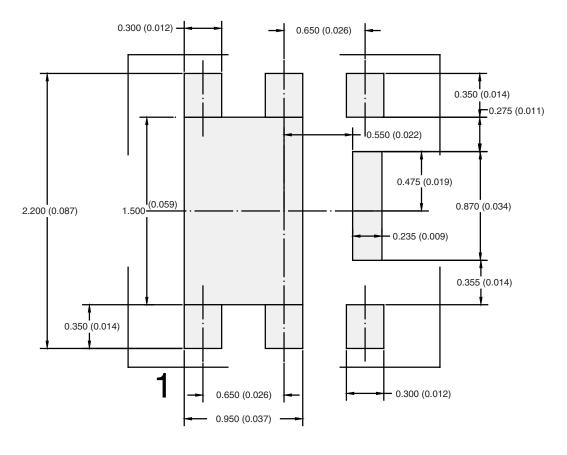
ECN: C-07431 - Rev. C, 06-Aug-07

DWG: 5934

Document Number: 73001 06-Aug-07



# RECOMMENDED PAD LAYOUT FOR PowerPAK® SC70-6L Single



Dimensions in mm/(Inches)

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Vishay

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